Title: Interior design engineering of CuS architecture alteration with rise in reaction bath temperature for high performance symmetric flexible solid state supercapacitor

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Highlights

- The nanoflower morphological CuS thin films are successfully synthesized using low cost, simple and convenient chemical bath deposition method.
- The excellent specific capacitance of 1818.2 F g^{-1} is achieved with specific surface area of 150.6 m^2 g^{-1} for CuS thin film.
- The CuS electrode exhibits electrochemical cycling stability of 92 % up to 2000 cyclic voltammetry (CV) cycles.
- The FSS-SCs-PVA-$LiClO_4$ device glows up 200 red LED panel after 30 s charging.